Jeong Seuk Kang

List of Publications by Year in descending order

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| # | Article | IF | CITATIONS |
|----|---|------|-----------|
| 1 | Expansion Microscopy for Beginners: Visualizing Microtubules in Expanded Cultured HeLa Cells. Current Protocols in Neuroscience, 2020, 92, e96. | 2.6 | 18 |
| 2 | Iterative expansion microscopy. Nature Methods, 2017, 14, 593-599. | 19.0 | 279 |
| 3 | Monolithic 3D CMOS Using Layered Semiconductors. Advanced Materials, 2016, 28, 2547-2554. | 21.0 | 107 |
| 4 | Direct growth of single-crystalline III–V semiconductors on amorphous substrates. Nature Communications, 2016, 7, 10502. | 12.8 | 45 |
| 5 | Engineering Light Outcoupling in 2D Materials. Nano Letters, 2015, 15, 1356-1361. | 9.1 | 138 |
| 6 | MoS2 Heterojunctions by Thickness Modulation. Scientific Reports, 2015, 5, 10990. | 3.3 | 93 |
| 7 | Strong interlayer coupling in van der Waals heterostructures built from single-layer chalcogenides. Proceedings of the National Academy of Sciences of the United States of America, 2014, 111, 6198-6202. | 7.1 | 970 |
| 8 | Field-Effect Transistors Built from All Two-Dimensional Material Components. ACS Nano, 2014, 8, 6259-6264. | 14.6 | 582 |
| 9 | Air-Stable Surface Charge Transfer Doping of MoS ₂ by Benzyl Viologen. Journal of the American Chemical Society, 2014, 136, 7853-7856. | 13.7 | 593 |
| 10 | Air Stable p-Doping of WSe ₂ by Covalent Functionalization. ACS Nano, 2014, 8, 10808-10814. | 14.6 | 208 |
| 11 | MoS ₂ P-type Transistors and Diodes Enabled by High Work Function MoO _{<i>x</i>} Contacts. Nano Letters, 2014, 14, 1337-1342. | 9.1 | 487 |
| 12 | Strain-Induced Indirect to Direct Bandgap Transition in Multilayer WSe ₂ . Nano Letters, 2014, 14, 4592-4597. | 9.1 | 572 |
| 13 | Defects activated photoluminescence in two-dimensional semiconductors: interplay between bound, charged and free excitons. Scientific Reports, 2013, 3, 2657. | 3.3 | 876 |
| 14 | Broad-Range Modulation of Light Emission in Two-Dimensional Semiconductors by Molecular Physisorption Gating. Nano Letters, 2013, 13, 2831-2836. | 9.1 | 674 |